Parafermions, induced edge states, and domain walls in fractional quantum Hall effect spin transitions

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Search for parafermions and Fibonacci anyons, which are excitations obeying non-Abelian statistics, is driven both by the quest for deeper understanding of nature and prospects for universal topological quantum computation. However, physical systems that can host these exotic excitations are rare and hard to realize in experiments. Here we study the domain walls and the edge states formed in spin transitions in the fractional quantum Hall effect. Effective theory approach and exact diagonalization in a disk and torus geometries proves the existence of the counterpropagating edge modes with opposite spin polarizations at the boundary between the two neighboring regions of the two-dimensional electron liquid in spin-polarized and spin-unpolarized phases. By analytical and numerical analysis, we argue that these systems can host parafermions when coupled to an *s*-wave superconductor and are experimentally feasible. We investigate settings based on v = 2/3, 4/3, and 5/3 spin transitions and analyze spin-flipping interactions that hybridize counterpropagating modes. Finally, we discuss spin-orbit interactions of composite fermions.

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I. INTRODUCTION

Since early years of quantum physics, it has been recognized that symmetry with respect to an exchange of particles results in the two possible quantum statistics, Bose-Einstein statistics for particles with integer spin and Fermi statistics for particles with half-integer spin. About fifty years later researchers realized that particles/quasiparticles confined to one dimension [1] or two dimensions [2,3] can obey a different statistics, which F. Wilczek called anyon statistics, for which an exchange results in the wave function picking up any possible quantum-mechanical phase. Furthermore, it was realized [4-8] that for degenerate states, an exchange, or more appropriately, braiding of particles or quasiparticles in two dimensions may result in nontrivial unitary transformation of the corresponding wave functions, i.e., in the non-Abelian statistics. It was recognized recently that the non-Abelian statistics opens new ways of approaching a fault-tolerant quantum computation. An approach to the topological quantum computation based on the Majorana fermions has been widely studied in recent years [9-12]. However, it became apparent that such systems are not computationally universal because braiding operations for Majorana fermions cannot approximate all unitary quantum gates [13,14]. In order to realize the universal topological quantum computation, other kinds of non-Abelian anyons are required. In particular, parafermions have been shown to have denser rotation groups and their braiding operations can enable two-qubit

entangling gates [15,16]. Furthermore, a two-dimensional array of parafermions can support Fibonacci anyons with universal braiding statistics [17]. Therefore it is of great interest to find experimentally realizable systems which can host parafermions. In a seminal paper [18], Clarke, Allicea, and Shtengel proposed that parafermions can appear in the fractional quantum Hall effect (FQHE) regime at filling factors v = 1/m if two counterpropagating edge states from two adjacent 2D electron gases with opposite g factors are gapped by the proximity superconducting pairing and spin-orbit induced tunneling.

Here we propose that a single layer of the 2D electron gas in a magnetic field near the spin transition between the filling factor v = 2/3 spin-unpolarized and spin-polarized states can be used to create a domain wall that will host parafermions when coupled to an *s*-wave superconductor, and use exact diagonalization of small systems in order to confirm this result microscopically. We discuss feasible experimental settings, analyze viable spin-flipping mechanisms capable of gapping counterpropagating modes with opposite spin, and discuss possible realizations of topological superconductivity and parafermions in spin transitions besides v = 2/3.

The FQHE spin transitions have been observed at the filling factor v = 2/3 and other fractions [19,20], e.g., when an inplane component of a tilted magnetic field is varied, resulting in a change in electron spin system. Such spin transition can be understood in terms of the composite fermion (CF) picture [21]. The FQHE states at a filling factor $v = \frac{n}{2n-1}$ for electrons can be mapped onto the integer quantum Hall states at a filling factor *n* for CFs. The energy of the *n*th CF level is

$$E_{ns} = \hbar \omega_c^{cf} \left(n + \frac{1}{2} \right) + sg\mu_B B, \tag{1}$$

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FIG. 1. (a) The schematic plot of the composite fermion energy levels. When the magnetic field is increased, there is a level crossing(black circle) of the $\Lambda_{0\downarrow}$ and $\Lambda_{1\uparrow}$ which leads to a spin transition from spin-unpolarized state to spin-polarized state. (b) A schematic plot of the edge states. The arrows represent the direction of their velocities and colors represent spin up(red) spin down(blue).

where the CF cyclotron energy $\hbar \omega_c^{cf}$ is proportional to the characteristic electron-electron interaction energy scale $\frac{e^2}{l_m}$, $l_m = \sqrt{\hbar c/eB_{\perp}}$ is the magnetic length, and B_{\perp} is the out of plane component of the magnetic field **B**. The second term is the Zeeman energy, the index $s = \pm 1$ represents the up and down spin states of the composite fermions. Since the cyclotron and Zeeman energies have different magnetic field dependencies, the levels $\Lambda_{p,\downarrow}$ and $\Lambda_{p+1,\uparrow}$ have to cross at some $B^* > 0$, as shown in Fig. 1(a). Therefore, at $B < B^*$, electrons of 2/3 state occupy $\Lambda_{0\uparrow}$ and $\Lambda_{0\downarrow}$ levels and the system is in the spin-unpolarized phase, while at $B > B^*$ they occupy $\Lambda_{0\uparrow}$ and $\Lambda_{1\uparrow}$ states and it is in the spin-polarized phase. Furthermore, it has been shown that electrostatic gates control electron-electron interactions, so that in a triangular quantum well the composite fermion cyclotron energy $\hbar \widetilde{\omega_c^{cf}} \propto$ $\frac{e^2}{\sqrt{l_m^2+z_0^2}}$, where z_0 is the extent of the electron wave function in the direction of the spatial quantization. Therefore it is possible to induce the spin-polarized and spin-unpolarized fractional quantum Hall phases in a single quantum well underneath different electrostatic gates. In this case, a controlled domain wall that separates regions with different spin polarizations should emerge [22,23]. Experimentally transitions can then be achieved by both tuning the effective Coulomb interaction and/or by tuning the Zeeman coupling via the in-plane component of the magnetic field [24].

The boundary between polarized and unpolarized regions of the 2D electron liquid results in edge-like states, which we will call edge states despite they are, strictly speaking, different from the true edge states flowing at the boundary of the quantum Hall samples. The reason for a difference between these two kinds of edge states is obvious. For edges at the sample boundary, the spin-unpolarized or spin-polarized phase has to decrease its density (filling factor) from v =2/3 in the bulk to v = 0 at the sample boundary. For the boundary between two v = 2/3 phases, the density stays nearly constant, the change in density has to be less than that corresponding to the width of the v = 2/3 plateau.

The first goal of our paper is to demonstrate the existence and investigate the nature of the edge states flowing through the domain wall between polarized and unpolarized fractional quantum Hall spin regions. The edge states of the quantum Hall systems were widely studied over the years [25–34]. For the filling factor v = 2/3, edge states of the fractional quantum Hall liquid at the sample boundaries have been studied in both spin-polarized and various kinds of unpolarized phases [35–39]. It has been predicted that both phases of v = 2/3 electron liquid can be characterized by two counterporopagating edge modes at the sample boundaries.

A new setting emerges on the spatial boundary between the two different topological orders, i.e., the domain wall between the spin-polarized and unpolarized phases realized in the neighboring regions of the 2D electron liquid. When the 2/3 polarized and unpolarized states are far apart, there are four edge modes with two states moving in one direction and two states moving in the opposite direction. When they are brought closer together, one can anticipate that there are only two edge modes left, see Fig. 1(b). This can be understood intuitively in terms of the composite fermion picture. The edge states associated with the common $\Lambda_{0\uparrow}$ level will merge and disappear, and only the edge states associated with the $\Lambda_{0\perp}$ and $\Lambda_{1\uparrow}$ levels will remain. This picture implies that the remaining edge states propagate in opposite directions and carry opposite spins. We will present simple qualitative ariguments to justify this picture, and demonstrate it rigorously by using the effective field theory. We will also apply exact diagonalization method in a disk and torus geometries.

It then follows that the domain wall excitations in the proximity of an *s*-superconductor are possibly characterized by a parafermion non-Abelian statistics. The domain wall system is similar to the setting discussed in Ref. [18] with a boundary of two fractional Hall liquids having opposite values of the electron *g* factor at a filling factor v = 1/3 in proximity to an *s*-superconductor. We will see indeed that the proximity coupling of the fractional quantum Hall ferromagnet domain wall area to an *s*-wave superconductor induces parafermions.

In an experimental setting, one needs to control the onset of topological supercondutivity and be able to induce and move the boundaries between topological and nontopological superconducting regions. Parafermions must be located at the boundaries between these regions. Thus an ability to change the boundaries between these regions allows to move parafermions, which would be ultimately necessary for their braiding. However, when crossing between the composite fermion Landau levels takes place, proximity coupling to the domain wall will always yield a topological proximity superconductivity, in much the same way as it happens in topological insulators [40,41]. Then no trivial proximity superconductivity at any value of induced superconducting order parameter is expected. In order to have both types of proximity superconductivity and potentially a boundary between the two regions with different superconducting order with the location of distinct from that of superconducting contacts, one has to induce a gap due to tunneling between the two counterpropagating edge states with opposite spin. When this tunneling is tuned, an onset of topological superconductivity depends on the competition of tunneling and proximity superconducting gaps. If an induced superconducting order parameter in the domain wall changes its amplitude along the domain wall, the possibility to move parafermions along the domain emerges.

We will study the effective theory of states in the domain wall when two gapping mechanisms are introduced: superconducting pairing and spin-flip tunneling across the domain wall caused by an in-plane component of a magnetic field, and demonstrate an emergence of parafermions in this system. We find that in a single quantum well the spin-orbit coupling is negligible between fractional quantum Hall edge states with opposite spins belonging to the first electron Landau level. Our simulation shows that despite a small g factor in a GaAs system, gapping of the edge states can be realized by an in-plane component of the magnetic field. Spin transitions in GaAs have been also observed at a filling factor 8/3 [42], which potentially opens a possibility of emergence of parafermions in high Landau levels fractional quantum Hall systems at magnetic fields below 1 T. We also propose that a good candidate for observing parafemions is CdMnTe system with the effective Zeemann splitting of the order to the cyclotron frequency, where the fractional quantum Hall effect has been observed in Ref. [43]. Furthermore, in this system, the fractional quantum Hall effect spin transition was observed at v = 5/3, and there have been also signatures of the spin transition at v = 4/3. In these cases, the fractional quantum Hall edge states that potentially experience crossing originate from different electron Landau levels, and in these circumstances spin-orbit interactions result in a sizable anticrossing gap. Because spin-orbit coupling can be effectively tuned by electrostatic gates, this setting would allow to tune the parafermion zero modes and their braiding using only gate voltage.

We would like to underscore that our results not only provide a path to a new platform realizing universal topologic al quantum computation, but also illustrate a general method to study the edge states on the boundary of systems with different topological orders. We also developed a scheme for numerical modeling of fractional quantum Hall states in proximity of an *s*-superconductor.

Our paper is organized as follows. In Sec. II, we analyze edge states on the boundary between topologically distinct 2/3 spin polarized and unpolarized states. Section III is devoted to the numerical calculations of edge states on on the disk, and Sec. IV presents the numerical calculations of edge modes on the torus. In Sec. V, we discuss the emergence of parafermion zero modes and Sec. VI describes the numerical calculation of these modes. In Sec. VII, we will discuss a possible parafermion setting based on v = 4/3 and 5/3 spin transitions and spin-orbit interactions of composite fermions. We summarize our results in Sec. VIII. In Appendix, we evaluate spin-flipping interactions of the quasiparticles orignating from the lowest Landau level.

II. ANALYTIC CONSIDERATION OF EDGE STATES ON THE BOUNDARY BETWEEN $\nu = 2/3$ SPIN-POLARIZED AND SPIN-UNPOLARIZED FRACTIONAL QUANTUM HALL STATES

In this section, we will use the effective theory in order to analyze the structure of the edge states on the boundary between 2/3 spin polarized and unpolarized phases analytically. We will quantitatively show that there remain only two edge modes, which propagate in opposite directions and



FIG. 2. (a) A schematic plot of the composite fermion energy levels in the bulk of the spin-polarized and spin-unpolarized regions. Potential barriers for composite fermions of the $\Lambda_{1\uparrow}$ Landau level and composite fermions of the $\Lambda_{0\downarrow}$ Landau level are shown. (b) Possible edge modes on the boundary of spin-polarized and spinunpolarized regions. The two modes in the middle corresponding to $\Lambda_{0\uparrow}$ can pair and form a gap. They are not considered in the low-energy theory. (c) Illustration of the crossed effective magnetic field **B**^{*} and electric field **E** resulting in counterpropagating modes of opposite spin and opposite velocities **v** in the shaded domain wall area. The electric field **E** is opposite for up and down spin states, as follows from potential barriers in Fig. 2(a).

carry opposite spins. An analytic theory is essential because not only it sheds light on the numerical calculations in the following sections, but is also necessary for the study of the emergence of parafermions.

Before considering the quantitative theory, we first qualitatively explain why there are edge states on the boundary between the two regions with topologically different orders. The formation of the edge modes are always related to the confinement potentials acting at the edges. Naively it seems that there is no confinement potential around the internal edge in our case. However, we actually have intrinsic spindependent confinement potential. Indeed, from the analysis in the introduction, we see that there is a level crossing between the edge states with opposite spins. The composite fermions in the $\Lambda_{0\downarrow}$ level in the spin-unpolarized phase can not tunnel into region of the spin-polarized phase because $\Lambda_{0\downarrow}$ level has a higher energy there, see Fig. 2(a). The same story also applies for the composite fermions of the $\Lambda_{1\uparrow}$ Landau level in the spin polarized phase. Therefore the composite fermions of these two levels characterizing opposite spins are subject to the effective spin-dependent potential confinements. A spatial gradient of this spin-dependent potential constitutes a spin-dependent electric field. Depending on the experimental setting, the spin-dependent confinement and electric fields are controlled either by varying z_0 extent of the electron wave function in the direction orthogonal to the 2D plane by electrostatic gates or by a spatial variation of the Zeeman coupling of the electron spin to an external magnetic field. The spin-dependent electric field acts together with the effective residual magnetic field, which is due to joint effect of the external magnetic field and the Chern-Simons field. For $\nu =$ 2/3, the effective magnetic field is negative [38], but it is the same in both the spin-polarized and unpolarized phases. Assuming a simple model, in which the change of potentials for each of the spins is linear in coordinate across the domain wall, we find that composite fermions with spin polarization up are subject to the crossed effective magnetic field and the electric field of one sign. For the spin polarization down, we again have crossed magnetic and electric fields, with an effective magnetic field being the same as for the spin up, but with the opposite electric field. Thus we have two counterpropagating composite fermion edge states of opposite spins due to these crossed effective magnetic and electric fields, see Fig. 2(c). This situation is analogous to the case of edge states at the domain wall between polarized and unpolarzed 2D regions in the case of the integer quantum Hall effect [23]. If Hamiltonian of the system contains only the out of plane magnetic field, the counterpropagating edge states experience no backscattering. An in-plane magnetic field results in hybridization of these edge states with opposite spins. This in-plane field, however, should be not strong enough to alter the character of neighboring spin phases.

We now discuss the effective theory for the boundary of the polarized and unpolarized regions. The Lagrangian density in the effective theory for the bulk fractional quantum Hall state can be written in the form [29,32]

$$\mathcal{L} = -\frac{1}{4\pi} K_{II'} a_{I\mu} \partial_{\nu} a_{I'\lambda} \epsilon^{\mu\nu\lambda} - \frac{e}{2\pi} q_I A_{\mu} \partial_{\nu} a_{I\lambda} \epsilon^{\mu\nu\lambda} + s_I \omega_{\mu} \partial_{\nu} a_{I\lambda} \epsilon^{\mu\nu\lambda}, \qquad (2)$$

where $a_{I\mu}$ represents *n* Abelian Chern Simons (CS) gauge fields, A_{μ} is the electromagnetic gauge field, ω_{μ} describes the curvature of the space, **K** is an $n \times n$ nonsingular integer matrix describing the coupling between the CS gauge fields, **q** is an n-component integer vector describing the coupling between the CS gauge fields and the electromagnetic gauge field, **s** is an *n*-component half-integer vector describing the coupling between the CS gauge fields and the curvature. An Abelian quantum Hall state can be classified by a set {**K**, **q**, **s**}, which determines the long distance properties of the state. Therefore this set characterizes the topological order of the Abelian quantum Hall fluid. For the $\nu = 2/3$ case, it takes the following values in the spin- polarized phase:

$$\mathbf{K}_{1} = \begin{pmatrix} 1 & 2 \\ 2 & 1 \end{pmatrix}, \mathbf{q}_{1} = \begin{pmatrix} 1 \\ 1 \end{pmatrix}, \mathbf{s}_{1} = \begin{pmatrix} \frac{1}{2} \\ -\frac{1}{2} \end{pmatrix}.$$
 (3)

For the spin-unpolarized phase, this set is defined by

$$\mathbf{K}_2 = \begin{pmatrix} 1 & 2\\ 2 & 1 \end{pmatrix}, \mathbf{q}_2 = \begin{pmatrix} 1\\ 1 \end{pmatrix}, \mathbf{s}_2 = \begin{pmatrix} \frac{1}{2}\\ \frac{1}{2} \end{pmatrix}.$$
 (4)

The form of the **K** matrix can be understood in terms of the composite fermion picture [38]. For the v = 2/3 state, there are two components each occupying a single CF Λ level in an effective antiparallel magnetic field. Thus the corresponding contribution to the **K** matrix is $K_{ij} = -\delta_{ij}$. Each component should have two fluxes attached, so we add an integer 2 to each element of the **K** matrix. From Eqs. (3) and (4), we see that the only difference between the spin-polarized and unpolarized phases is the spin vector **s**, as expected. In Eq. (2), the second and the third terms are similar. If we regard **q** as

a vector describing the unit of the electric charge carried by the two CF components, **s** can be regarded as describing the "curvature charge" carried by the CF components.

We now consider the physics of the edge states. We note that for the edge states in the domain wall, due to the absence of a boundary with vacuum, simple arguments based on $\nu = 1$ forward-mowing mode bordering vacuum and 1/3 backward-flowing mode of holes can no longer be applied even for the spin-polarized phase. Similarly, analogous composite fermion picture with two edges, one separating 2 and 1 filled composite fermion Λ -levels and the other separating Λ levels 1 and 0, which upon antiparallel flux attachment are characterized by electron filling factors 2/3, 1/3, and 0, also does not work. The reason is, instead of vacuum at the boundary, we have a phase of nearly the same density, within the interval of densities on the $\nu = 2/3$ plateau. Therefore the *K*-matrix description of Wen [32] is the reliable way to approach the solution of this problem.

When the fractional quantum Hall liquid is confined by the boundaries of the sample, the action $S = \int dx dy dt \mathcal{L}$, where \mathcal{L} is given by Eq. (2), is not gauge invariant for the CS gauge fields. To restore the gauge invariance, one has to introduce an action that describes the edge physics:

$$S_{\text{edge}} = \frac{1}{4\pi} \int dt dx [\mathbf{K}_{IJ}\partial_t \phi_I \partial_x \phi_J - \mathbf{V}_{IJ}\partial_x \phi_I \partial_x \phi_J].$$
(5)

In Eq. (5), we assume that the edge is along the *x* axis, ϕ_I is the field that describes the *I*th component of the edge branches, $a_{Ii} = \partial_i \phi_I$ and $\rho_I = \frac{1}{2\pi} \partial_x \phi_I$ is the density of the *I*th branch. **K** is the same matrix as in the bulk phase, and one can show that its positive eigenvalues correspond to the leftmoving branches, and its negative eigenvalues correspond to the right-moving branches. **V** is a positive-definite matrix that encodes the nonuniversal interactions between edge branches. We now study the properties of the edge states between two Abelian FQH phases. Assuming the edge is along y = 0 axis, and using the same gauge argument as in Ref. [32], we find that the {**K**, **q**, **s**} for the new state is

$$\mathbf{K} = \mathbf{K}_1 \bigoplus -\mathbf{K}_2, \mathbf{q} = \mathbf{q}_1 \bigoplus \mathbf{q}_2, \mathbf{s} = \mathbf{s}_1 \bigoplus \mathbf{s}_2.$$
(6)

A similar situation for bilayers was considered in Ref. [35], however the spin vectors did not play any role there. Here we include spin vectors into the picture. In Eq. (6), $dim(K) = dim(K_1) + dim(K_2)$, and all edge branches are retained. After considering the tunneling perturbation, we see that two of the edge branches can be removed from the low-energy theory. Following Ref. [35], we define the following quantities:

$$\phi(m) = m_i \phi_i, \quad q(m) = m_i q_i,$$

$$s(m) = m_i s_i, \quad K(m) = m_i K_{ij} m_j, \quad (7)$$

where \mathbf{m} is an integer valued vector, and repeated indices mean summation. We define further a set of local fields:

$$\Psi_m = e^{-i\phi(m)},\tag{8}$$

which obey

$$\Psi_m(x)\Psi_{m'}(x') = (-1)^{q(m)q(m')}\Psi_{m'}(x')\Psi_m(x)$$
(9)

for $x \neq x'$. From the properties of **K** matrix in the symmetric representation, we have

$$(-1)^{K(m)} = (-1)^{q(m)} \tag{10}$$

Thus, if K(m) is odd, the field Ψ_m is fermionic, and if K(m) is even, it is bosonic. Now we consider the tunneling perturbation:

$$T = \int dx [t(x)\Psi_m(x) + \text{H.c.}].$$
(11)

It should be bosonic and charge conserving, hence q(m) = s(m) = 0 and K(m) even. The scaling dimension of Ψ_m is $\Delta(m)$ that satisfies the inequality

$$\Delta(m) \ge \frac{1}{2} |K(m)|. \tag{12}$$

If the tunneling perturbation is relevant, the modes in Ψ_m become massive and are removed from the low-energy theory. From the scaling perspective, it is potentially relevant if the scaling dimension $\Delta(m) < 2$. So, with the constraints given above, we conclude that the condition for **m** that leads to a potentially mass generating perturbation is

$$K(m) = q(m) = s(m) = 0.$$
 (13)

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We see that although the space may be flat, the spin vector still plays a role in the properties of edge states.

We now apply this analysis to the edge states at the boundary of v = 2/3 spin-polarized and unpolarized regions. The set {**K**, **q**, **s**} of the effective theory for this state, where two phases coexist, is

$$\mathbf{K} = \begin{pmatrix} 1 & 2 & 0 & 0 \\ 2 & 1 & 0 & 0 \\ 0 & 0 & -1 & -2 \\ 0 & 0 & -2 & -1 \end{pmatrix}, \mathbf{q} = \begin{pmatrix} 1 \\ 1 \\ 1 \\ 1 \end{pmatrix}, \mathbf{s} = \begin{pmatrix} \frac{1}{2} \\ \frac{1}{2} \\ \frac{1}{2} \\ -\frac{1}{2} \end{pmatrix}.$$
 (14)

In terms of CF theory, we can identify fields ϕ_i as ϕ_1 , ϕ_2 corresponding to $\Lambda_{0\uparrow}$, $\Lambda_{0\downarrow}$ respectively, and ϕ_3 , ϕ_4 corresponding to $\Lambda_{0\uparrow}$, $\Lambda_{1\uparrow}$ respectively. From Eqs. (13) and (14), we find out two independent solutions for **m**: **m**₁ = (1, 0, -1, 0) and **m**₂ = (0, 1, -1, 0). The solution **m**₂ represents tunneling between $\Lambda_{0\downarrow}$ and $\Lambda_{0\uparrow}$, which is unlikely to happen since there is an energy gap. Therefore only the operator Ψ_{m_1} is relevant and potentially mass generating, and ϕ_1 , ϕ_3 are removed from the low-energy theory. Thus we have shown that in the *K*-matrix description there are only two counterpropagating edge states with opposite spins.

Quite remarkably on the level of K-matrix description, in the low-energy sector of the domain wall, neutral modes do not emerge, and spin-charge separation of the spinunpolarized phase does not appear. There are always questions of possible edge reconstruction, the role of disorder, and in this particular case, a problem of how the domain wall edges couple to the true edges at the boundary of the sample, which is even more complicated than behavior of edge states in homogeneous phases in the corners of a sample. However, our conclusion on the two counterpropagating states with opposite spins in the domain wall, supported by the K-matrix description as well as by a hand-waving crossed electric and effective magnetic fields argument, rings true. We shall see



FIG. 3. (a) Disk geometry for the simulation domain. (b) The profile of the Zeeman splitting of electron states. (c) Spectra of eight electrons on the disk with the profile of the Zeeman splitting shown in Fig. 3(b). They are characterized by an total angular momentum L_z and a total electron spin S_z . The ground state with $L_z = 46$ is circled red. Edge excitations with the same $S_z = 2$ as in the ground state and with $L_z = 45$ and 47, corresponding to the addition or subtraction of a single flux, are circled black.

that this picture is also supported by the exact diagonalization in disk and torus geometry.

III. NUMERICAL CALCULATIONS IN THE DISK GEOMETRY

Here we will use exact diagonalization in the disk geometry in order to confirm the conclusions of the previous section about the induced edge states on the boundary of the v = 2/3 spin-polarized and spin-unpolarized regions. Some of the results in this section have already been briefly discussed in our paper Ref. [24]. For completeness of our analysis, we include these here, with an improved numerical procedure and extended discussion.

We simulate the system of eight electrons in a magnetic field using the disk geometry shown schematically in Fig. 3(a). In this model we use a spatially dependent Zeeman energy to control the spin polarization in z direction, see Fig. 3(b). The central region of the disk with a radius R_1 is characterized by a large Zeeman term E_Z^{max} , while the outer region with the outer diameter R_2 is set to $E_Z^{\text{min}} = 0$. The Zeeman term is varied smoothly within the region defined by an interval of r given by $R_1 < r < R_1 + \Delta R$, resulting in a smooth variation of the wave functions across the disk and

avoiding spurious effects originating from an abrupt change of the Zeeman splitting. When there are eight electrons on the disk, the allowed single particle states have angular momentum $0 \le m \le 11$. Thus $R_2 = \sqrt{22}l_m = 4.8l_m$. We design the central region in such a way that it contains half of the electrons, corresponding to the condition $R_1 + \Delta R = \sqrt{11} l_m =$ $3.3l_m$. We set $R_1 = 2.9l_m$ and $\Delta R = 0.4l_m$. We anticipate that the resulting spin density will reflect that electrons should be spin-polarized in the central region and spin-unpolarized in the outer region in the difference of spin densities in inner and outer regions. Note that due to a strong penetration of electron wave function from the outer $R_1 < r < R_2$ region into the inner $r < R_1$ region of the disk, the central region will contribute significantly to average spin polarization of all states. We shall see that this contribution of the central region leads to a decrease in the difference of the average spin splitting $\int \psi(r)^* E_Z(r) \psi(r) d^2 r$ for the modes on the two sides of the domain wall to about <6%, similar to the experimental conditions of Ref. [24].

The electron Hamiltonian is given by

$$\mathcal{H}_{d} = \frac{1}{2m^{*}} \sum_{i} \left(\mathbf{p} + \frac{e\mathbf{A}}{c} \right)_{i}^{2} + E_{z}(r_{i})\sigma_{z}^{(i)} + U_{i}$$
$$+ \sum_{ij} \frac{e^{2}}{\epsilon |r_{i} - r_{j}|}.$$
(15)

The first term and the second term in Eq. (15) are kinetic energy and Zeeman energy respectively. The third term is the parabolic confinement $U(r) = Cr^2$, confining electrons to the disk, with $C = 0.036e^2/\epsilon l_m^3$, and the last term is the Coulomb interaction between electrons. This Hamiltonian is diagonalized using a configuration interaction method. The states are classified by their projections of the total angular momentum on the z axis, L_z , and the total spin of electrons, S_z . We exactly diagonalize this Hamiltonian for eight electrons in a spatially varying Zeeman energy that models the coexistence of spin polarized and unpolarized states at a filling factor v =2/3. The exact diagonalization spectra are given in Fig. 3(c). We have identified the ground state, which is spin-polarized in the center and unpolarized in the outer region of the disk, as well as the edge states flowing close to the boundary between spin polarized and spin unpolarized regions. Their number and spin density distributions are calculated. The results are shown in Figs. 4(a)-4(f).

The ground state has a total angular momentum $L_z = 46$ and a total spin $S_z = 2$. The total spin indicates that six electrons are in spin up state and two electrons are in spin down state, as expected. In the CF picture, there are N electrons with N/2 occupying $\Lambda_{0\uparrow}$ and N/4 occupying $\Lambda_{1\uparrow}$ in the center region and $\Lambda_{0\downarrow}$ in the outer region. The total angular momentum of the ground state is

$$L_{z} = pN(N-1) + L_{z}^{CF} = N(N-1)$$
$$-\left[\frac{N}{4}\left(\frac{N}{2}-1\right) + \left(\frac{N}{4}-3\right)\frac{N}{8} + \left(\frac{3N}{4}-1\right)\frac{N}{8}\right]$$
$$= N(N-1) - \frac{N(N-3)}{4} = \frac{N(3N-1)}{4}.$$
(16)



FIG. 4. (a) The ground-state electron density (red) and spin density (blue) for eight electrons on the disk containing the domain wall between polarized and unpolarized states at a filling factor 2/3 in a magnetic field. (b) The density profile (red) and spin polarization (blue) for the edge state M = 45. (c) The density profile (red) and spin polarization (blue) for the edge state M = 47. (d) The differences of density (red) and spin (blue) between M = 45 edge state and the ground state. (e) The differences of density (red) and spin density (blue) between M = 47 edge state and the ground state. (f) Spin density difference between edge state M = 45 and 47.

For N = 8, $L_z = 46$ indeed, coinciding with our numerical result. The ground state is separated by a gap from the rest of the spectra as shown Fig. 3(c), and does not carry the electric current. From the spin profile in Fig. 4(a), the ground state is indeed spin-polarized in the center of the disk and spin-unpolarized in the outer region.

The lowest energy excitations that have spin polarization of the ground state and correspond to a substraction or addition of a single flux have $L_z = 45$ and 47, see Figs. 4(b) and 4(c). These are the modes that carry an electrical current. When compared to the ground state, they have $\Delta L = -1$ and $\Delta L = 1$, respectively. This indicates that these two edge states have opposite components of linear velocities. The differences in density and in the spin polarization density between the two edge states and the ground state are shown in Figs. 4(d) and 4(e). We observe that the density differences are large only around the internal edge, which confirms that these two edge states correspond to the internal boundary between regions with large and small Zeemann interactions, i.e., the domain wall. In Fig. 4(f), we show the results for the difference of spin densities of the two modes near the domain wall between polarized and unpolarized region. Despite the finite size effects in a small system, the exact diagonalization clearly identifies that the two edge states in the domain wall area

have components of spin density with opposite orientation. Our numerical study clearly shows that there are two counterpropagating edge states in the domain wall with different spin polarizations, which is consistent with our analysis in Sec. II.

IV. NUMERICAL CALCULATIONS ON THE TORUS

In this section, we will numerically study the system in a torus geometry. The advantage of the torus geometry is that it allows to avoid considering the edge between the fractional quantum Hall liquid and a vacuum that is present in the disk configuration. Hence physics of the induced edge between spin polarized and unpolarized regions is elucidated.

The torus geometry is represented as a rectangular cell with periodic boundary conditions. This geometry has been considered in Ref. [44] for the 1/3 FQH state. We apply the method of Ref. [44] to our case. We take the coordinate system such that the boundary of the rectangular cell is given by x = 0, x = a, y = 0, y = a, with the vector potential $\vec{A} = (0, xB)$. We have $2\pi l_B^2 \frac{N}{a^2} = v$, therefore $a = \sqrt{24\pi} l_B = 8.68 l_B$, and there are $m = \frac{N}{v} = 12$ single electron orbitals in the cell. The wave functions of these orbitals are given by

$$\phi_j(\vec{r}) = \left(\frac{1}{a\pi^{1/2}l_B}\right)^{\frac{1}{2}} \sum_{k=-\infty}^{\infty} e^{\left[i\frac{(X_j+ka)y}{l_B^2} - \frac{(X_j+ka-x)^2}{2l_B^2}\right]},$$
 (17)

where *j* labels the *j*th orbit, $1 \le j \le m$, and $X_j = \frac{j}{m}a$ is the coordinate of the guiding center. The Hamiltonian of the system can be written as

$$\mathcal{H}_{t} = \frac{1}{2m^{*}} \sum_{i} \left(\mathbf{p} + \frac{e\mathbf{A}}{c} \right)_{i}^{2} + E_{z}(r_{i})\sigma_{z}^{(i)} + \sum_{ij} V(\mathbf{r}_{i} - \mathbf{r}_{j}).$$
(18)

The first and the second terms are the kinetic and Zeeman term, correspondingly. The third term is the Coulomb interaction of electrons in real space, and due to the boundary conditions, it is given by

$$V(\mathbf{r}) = \sum_{s} \sum_{t} \frac{e^2}{\epsilon |\mathbf{r} + sa\hat{x} + ta\hat{y}|},$$
(19)

where \hat{x} and \hat{y} are unit vectors along x and y directions, s and t are integers. The Coulomb matrix elements are determined by

$$V_{j_{1}j_{2}j_{3}j_{4}} = \frac{1}{2} \int d^{2}r_{1}d^{2}r_{2}\phi_{j_{1}}^{*}(\mathbf{r}_{1})\phi_{j_{2}}^{*}(\mathbf{r}_{2})V(\mathbf{r}_{1}-\mathbf{r}_{2})\phi_{j_{3}}(\mathbf{r}_{3})\phi_{j_{4}}(\mathbf{r}_{4})$$

$$= \frac{1}{2a^{2}} \frac{2\pi e^{2}}{\epsilon q} \sum_{q}' \sum_{s} \sum_{t} \delta_{q_{s},\frac{2\pi s}{a}} \delta_{q_{s},\frac{2\pi t}{a}} \delta_{j_{1}-j_{4},t}$$

$$\times \exp\left[-\frac{l_{B}^{2}q^{2}}{2} - 2\pi i s \frac{j_{1}-j_{3}}{m}\right] \delta_{j_{1}+j_{2},j_{3}+j_{4}}'.$$
 (20)

Here the symbols with prime are defined modulo m and the summation over q excludes q = 0. From the above expression, we observe that the total angular momentum is conserved only modulo m. Therefore we are going to use the total angular



FIG. 5. (a) The torus geometry for a spatially varying Zeeman energy. (b) The amplitude of Zeeman energy along the toroidal direction. (c) Spectra of eight electrons on the torus without Zeeman splitting. The ground state has threefold degeneracy. (d) Spectra of eight electrons on the torus with a profile of Zeeman energy shown in Fig. 5(b). Electrons are characterized by a total angular momentum (mod 12) L_z and a total spin S_z of particles. Ground state is the $L_z = 0$ and $S_z = 2$ state, circled red. Edge excitations with the same $S_z = 2$ as in the ground state with $L_z = 1, 11$, which correspond to the addition or subtraction of a single flux, are circled black.

momentum M(mod m) and the total spin S to classify the quantum states.

We first exactly diagonalize the eight-electron Hamiltonian in the lowest Landau level in the absence of the Zeeman term. In this case, only the Coulomb terms play a role. The spectra are shown in Fig. 5(c). We find that the groundstate state has the degeneracy three, which is consistent with Ref. [45], in which the degeneracy is shown to be



FIG. 6. (a) The ground-state electron density (red) and spin density (blue) for eight electrons on a torus containing the domain wall between spin-polarized and unpolarized states at a filling factor 2/3in a magnetic field. (b) The density profile (red) and spin polarization (blue) for the edge state M = 1. (c) The density profile (red) and spin polarization (blue) for the edge state M = 11. (d) The differences of density (red) and spin (blue) between M = 1 edge state and the ground state. (e) The differences of density (red) and spin (blue) between M = 11 edge state and the ground state. (f) Spin difference between edge state M = 11 and M = 1.

given by $|\det(K)|$. Equation (4) indeed gives the degeneracy three.

Now we turn on the spatially dependent Zeeman term defined by Figs. 5(a) and 5(b). We divide the torus into four equal regions. One of these regions has large Zeeman energy E_Z^{max} , while the opposite side of the torus is subject to zero Zeeman energy. Zeeman energy varies smoothly in the regions between these two from zero to E_Z^{max} . Exact diagonalization leads to spectra shown in Fig. 5(d). We observe that there is a single ground state with M = 0 and S = 2 circled red in Fig. 5(d). The reason for the lifted degeneracy is a broken symmetry of magnetic translations in the presence of the spatially varying Zeeman term.

We find the density profile and the spin polarization of the ground state, shown in Fig. 6(a). The density is fluctuating slightly around v = 2/3, as expected. The spin polarization is almost unity within the region where $E_Z = E_Z^{\text{max}}$ (region A) and has a dip in the region $E_Z = 0$ (region B). This clearly indicates that the electrons are spin-polarized in the region A and spin-unpolarized in the region B. Therefore our numerical calculation indeed simulate the state in which spin-polarized and spin-unpolarized fractional quantum Hall phases coexist.

We now study the edge states. Comparison of Figs. 5(c) and 5(d) shows several low-energy excitations. We are most interested in the two states with the same total spin as the total spin in the ground state. The two states correspond to to single edge state quanta flowing in the positive and negative

poloidal directions. These states are circled black in Fig. 5(d). Their total spin equals 2, and their angular momenta are L = 1 and 11, respectively. Their density distributions and spin polarizations, as well as the differences between these densities and those in the ground state are calculated, see Figs. 6(b)–6(e). In order to compare the spin polarizations of the edge states, we also calculate the difference in spin polarizations $S_{11} - S_1$, plotted in Fig. 6(f). We see indeed that a domain wall (spin transition) emerges between regions A and B. Therefore our numerical study on the torus also supports the conclusion that there are two counterpropagating edge states with opposite spin polarizations in the domain wall between spin-polarized and spin-unpolarized states.

V. EMERGENCE OF PARAFERMION MODES

From the qualitative arguments, analytic theory and numerical calculations, we found that the edge states comprising the domain wall have opposite components of velocity and spin. Therefore, these states can potentially be coupled to an s-wave superconductor, a pre-requisite for generating topological superconductivity. In the integer quantum Hall ferromagnets, proximity superconducting coupling has resulted in topological superconductivity in the domain wall region and in the Majorana zero modes at the boundaries between topological and trivial superconducting regions [23]. In the FQH regime, we anticipate the emergence of parafermions due to the fractional charges and fractional statistics of states comprizing the domain wall in much the same way as in Ref. [18]. In this section, we will quantitatively show how the parafermions emerge and can be controlled when coupled to an s-wave superconductor in the presence of spin-flipping interactions discussed in Appendix.

The physics of the edge modes is described by the action Eq. (5) with *K* matrix given by Eq. (14). To simplify the expressions, we redefine the fields $\phi_{11} = \phi_1$, $\phi_{12} = \phi_2$, $\phi_{21} = \phi_3$, and $\phi_{22} = \phi_4$. After quantizing these fields, we have the following commutation relations [17,46]:

$$[\phi_{1\alpha}(x),\phi_{1\beta}(x')] = i\pi \left[(K^{-1})_{\alpha\beta} \operatorname{sgn}(x-x') + i\sigma_{\alpha\beta}^{y} \right], \quad (21)$$

$$[\phi_{2\alpha}(x),\phi_{2\beta}(x')] = i\pi \left[(-K^{-1})_{\alpha\beta} \operatorname{sgn}(x-x') + i\sigma_{\alpha\beta}^{\mathcal{Y}} \right], \quad (22)$$

$$[\phi_{1\alpha}(x), \phi_{2\beta}(x')] = i\pi \left[(-K^{-1})_{\alpha\beta} + i\sigma_{\alpha\beta}^{y} \right].$$
(23)

From the analysis of Sec. II, the remaining edge modes are generated by the fields ϕ_2 and ϕ_4 . From Eqs. (21) to (23), we find their commutation relations:

$$[\phi_2(x), \phi_2(x')] = \frac{i\pi}{3} \operatorname{sgn}(x - x'), \qquad (24)$$

$$[\phi_4(x), \phi_4(x')] = -\frac{i\pi}{3} \operatorname{sgn}(x - x'), \qquad (25)$$

$$[\phi_4(x), \phi_2(x')] = \frac{i\pi}{3}.$$
 (26)

Therefore ϕ_2 and ϕ_4 satisfy exactly the same commutation relations as ϕ_R and ϕ_L in Ref. [18]. We now discuss the emergence of parafermions. We observe that the path that lead to parafermions in Ref. [18] cannot work in the present case. The reason is, the spin-orbit interactions for electrons in the ground level are exceedingly small (see Appendix) and



FIG. 7. (a) A schematic plot of experimental realization of parafermion zero modes. (b) The spatial profile of the superconducting pairing and Zeeman-induced amplitudes $\Delta(x)$ and T(x) induced by proximity effects in Fig. 7(a).

cannot sufficiently gap the two counterpropagating modes. We will analyze the possibility to generate transitions between counterpropagating edges with opposite spin by applying the in-plane magnetic field. It is important that the orbital part of the wave functions of the two counterpropagating edge modes are nearly the same, a small difference exists only because these states are subject to opposite electric fields, due to the gradient of Zeeman splitting of the opposite spin states in the domain wall region. Thus it is sufficient to mix spins by an inplane magnetic field in order to generate transitions between the edge states. This hybridization results in the tunneling gap. At the same time, moderate in-plane magnetic fields keep the spin states of neighboring quantum Hall liquids unchanged. Coupling the domain wall area to a conventional s-type superconductor, we introduce all ingredients for emergence of parafermions, and can apply a general argument discussed in Ref. [18].

We envision the following architecture of the parafermion setting. For the proximity superconductivy, preliminary considerations show that proximity coupling to the edge quantum Hall states requires contacts with small Shottki barriers, allowing to control propagation of the Cooper pairs and electrons by the applied voltage. We assume that a proximity superconductors contact the domain wall area from the sides, as opposed to traditionally invisioned superconductor on the top of the semicoducting wire, quantum dot or a quantum well. Side configuration has additional advantage of gradually changing induced superconducting coupling from the contact to the region inside the domain wall area. When the competition of superconducting and tunneling gap leading to transition from trivial to topological proximity superconductivity depends on relative value of gaps, spatial dependence of the superconducting coupling will allow to tune the boundary between normal and topological superconductivity, where parafermions are expected to reside, by tuning this relative value. However, to simplify our consideration of emergence of parafermions, we follow [18] and consider the architecture in Fig. 7(a), assuming for simplicity that two trivial superconducting regions are separated by a region, which produces a spin flip between edge states, i.e., the tunneling gap. The spatial profile of the pairing potential and tunneling for this simplified picture is given in Fig. 7(b). We redefine the fields $\phi_{2/4} = \varphi \pm \theta$. The Hamiltonian of the interface is given by $H = H_0 + H_1$, where

$$H_0 = \frac{mv}{2\pi} \int dx [(\partial_x \varphi)^2 + (\partial_x \theta)^2], \qquad (27)$$

m = 3, and

$$H_1 \sim \int dx [-\Delta(x)\cos(2m\varphi) - T(x)\cos(2m\theta)].$$
 (28)

Assuming that angles θ and φ obey $\varphi_{x < x_1} = \pi n_{\varphi}^1/m$, $\theta_{x \in (x_1+l,x_2)} = \pi n_{\theta}/m$, $\varphi_{x > x_2+l} = \pi n_{\varphi}^2/m$, we have

$$\left[n_{\varphi}^{2}, n_{\theta}\right] = i\frac{m}{\pi}.$$
(29)

At low energy, we can focus on the interval between x_j and $x_j + l$ governed by the effective Hamiltonian

$$H_{\text{eff}} = \frac{mv}{2\pi} \sum_{i=1}^{2} \int_{x_i}^{x_i+l} dx [(\partial_x \varphi)^2 + (\partial_x \theta)^2].$$
(30)

We identify the operators

$$a_i \to e^{i(\pi/m)(n_{\varphi}^j + n_{\theta})}, s$$
 (31)

which commute with H_{eff} and represent zero modes bound to areas between superconducting regions and the region where the gap between edge states is induced by tunneling. These modes obey the following relations:

$$a_j^{2m} = 1, a_j a_{j'} = a_{j'} a_j e^{i(\pi/m) \operatorname{sgn}(j'-j)}.$$
 (32)

Therefore they are parafermion operators producing the 2m-fold ground-state degeneracy.

VI. NUMERICAL CALCULATIONS OF THE PARAFERMION ZERO MODES

Having demonstrated that parafermions emerge in the simple model of the previous section, we now show numerically that parafermions arise when an *s*-wave superconductivity and tunneling are added to the quantum Hall states in a microscopic model. In the numerical simulation here, the appearance of parafermion modes is indicated by an emergence of a sixfold degenerate ground state.

The Hamiltonian of the system is given by

$$\mathcal{H} = \mathcal{H}_t + H_{\rm sc} + H_{bx} - \mu \hat{N} + C(\hat{N} - \hat{N}_0)^2.$$
(33)

The first term \mathcal{H}_t is given by Eq. (18). As illustrated in Secs. II and IV, two domain walls form in the boundary regions between the spin polarized and unpolarized quantum Hall liquids. The boundary regions are the intermediate regions between E_Z^{max} and 0 in Fig. 8(b), which occur in the intervals [a/4, a/2] and [3a/4, a]. Each domain wall supports two counterpropagating edge modes with opposite spin polarizations. The second term H_{sc} is the superconducting pairing term

$$H_{\rm sc} = \int d\mathbf{r} (\Delta(\mathbf{r}) \Psi_{\uparrow}^{\dagger}(\mathbf{r}) \Psi_{\downarrow}^{\dagger}(\mathbf{r}) + \Delta^{*}(\mathbf{r}) \Psi_{\downarrow}(\mathbf{r}) \Psi_{\uparrow}(\mathbf{r})), \quad (34)$$

where $\Delta(\mathbf{r})$ is the Bogoliubov-De Gennes pairing potential. This pairing potential generally has to be determined selfconsistently. Quite obviously, $\Delta(\mathbf{r})$ depends on the chosen gauge describing an application of magnetic field to the



FIG. 8. (a) A schematic plot of the system. The superconducting order couples predominantly only closest states comprising domain wall. When induced on the top half of the torus, it results in dominant coupling of domain wall counterpropagating states with opposite spins and small coupling of all other states. An in-plane magnetic field is is confined in the domain wall and assumed to affect the bottom half of the torus. (b) (Top) the rectangular representation of the torus. The green shaded region is subject to in-plane magnetic field and is located near one of the domain walls. (Bottom) The profile of the Zeeman coupling caused by the component of magnetic field in *z* direction, which is perpendicular to the plane of the rectangular. Domain walls form in two regions [a/4, a/2] and [3a/4, a].

system, like generally gauge-dependent $\Psi_{\downarrow}(\mathbf{r})$ and $\Psi_{\uparrow}(\mathbf{r})$ in Eq. (34).

Whilst self-consistent evaluation of $\Delta(\mathbf{r})$ is beyond the scope of the present paper, in order to capture superconducting correlations in our system we use the following physical considerations. We take first $\Delta(\mathbf{r})$ equals constant value $\Delta_1 = \Delta$ on the top half of the torus, and constant value $\Delta_2 = 0$ on the bottom half of the torus, see Fig. 8(a). If we express the field operators $\Psi(\mathbf{r})$ in terms of the creation and annihilation operators a_j^{\dagger} and a_j that add or annihilate an electron in states given by Eq. (17), the superconductong pairing becomes $H_{\rm sc} = \sum_{j,n} \Delta_{jn} a_{j\uparrow}^{\dagger} a_{n\downarrow}^{\dagger} + \text{H.c.}$, with $j, n = 1, 2, \ldots, m$. When the total number of states *m* is an even number, we obtain for j + n = m, 2m

$$\Delta_{jn} = \sum_{k+q=-1} \frac{\Delta_1}{2\sqrt{\pi}} \int_0^a dx \exp\left[-\left(\frac{(X_j + ka - x)^2}{2} + \frac{(X_n + qa - x)^2}{2}\right)\right],$$
(35)

where $X_j = a \frac{j}{m}$. For j + n odd numbers, we obtain

$$\Delta_{jn} = \sum_{k,q} \frac{i(-\Delta_1)}{2\pi^{\frac{3}{2}}m(k+q+\frac{j+n}{m})} \int_0^a dx$$
$$\times \exp\left[-\left(\frac{(X_j+ka-x)^2}{2} + \frac{(X_n+qa-x)^2}{2}\right)\right].$$
(36)

In these two equations we observe a Gaussian dependence on the distance between guiding centers of Landau states on the torus. The superconducting pairing goes down exponentially for states being far from the domain wall. We will now assume that a single matix element Eq. (36) with j = 4and n = 3, which corresponds to coupling of closest domain wall states defined by the wave functions (17), describes the superconducting correlations in our system. All other matrix elements are considered vanishing [47]. We note that such treatment corresponds to experimental conditions, for which superconducting pairing is envisioned only for the edge states comprising the domain wall.

The third term H_{bx} in Eq. (33) is a spin-flipping tunneling term. In this section, this is the in-plane Zeeman coupling along the *x* axis [*x* and *y* directions on the torus are defined in Fig. 8(b)]. In an in-plane magnetic field, $H_{bx} = \sum_i \frac{1}{2}g\mu B(\mathbf{r}_i)\sigma_x^{(i)}$. In our numerical calculations, $B(\mathbf{r}) = B$ if $x \in [0.35a, 0.45a]$ and $y \in [0, 0.5a]$, where *a* is the length of the torus in *x* and *y* directions. Otherwise $B(\mathbf{r}) = 0$, as shown in Fig. 8(b). In the second quantization representation, $H_{bx} = \sum_{j,n} B_{jn} a_{j\uparrow}^{\dagger} a_{n\downarrow} + \text{H.c.}$, with j, n = 1, 2, ..., m. For j = n, we have

$$B_{jn} = \sum_{k=q} \frac{g\mu B}{4\sqrt{\pi}} \int_{0.35a}^{0.45a} dx \exp\left[-\left(\frac{(X_j + ka - x)^2}{2} + \frac{(X_n + qa - x)^2}{2}\right)\right].$$
(37)

For the difference j - n being odd numbers, the B_{jn} is given by

$$B_{jn} = \sum_{k,q} i \frac{g\mu B}{2\pi^{\frac{3}{2}}m(k-q+\frac{j-n}{m})} \int_{0.35a}^{0.45a} dx$$
$$\times \exp\left[-\left(\frac{(X_j+ka-x)^2}{2} + \frac{(X_n+qa-x)^2}{2}\right)\right].$$
(38)

The fourth term in Eq. (33) is the chemical potential, and the fifth term is the charging energy similar to that introduced in Ref. [48]. It represents the capacitor energy associated with the change of the number of electrons. These two terms are used to tune the electron number in the ground state of the system to the desired number.

We now consider the Hilbert space of the numerical simulations. Here we take minimal possible number of four electrons in the six orbitals defined in Eq. (17), so m = 6. Two electrons (half of the total number) have the same spin, representing spin-polarized phase, and other two electrons represent the other half in spin-unpolarized state and have opposite spins. Thus three electrons have spin up, and one electron is in spin down state, so the total spin of electrons S = 1. We use the pair (N, S) to represent the set of states with total electron number N and total spin S. Without superconductivity and tunneling, the Hilbert space is (4, 1). The superconducting term H_{sc} emerging from coupling of domain wall counterpropagating states with opposite spins mixes the states with different numbers N, and the spin-flipping term H_{BX} mixes the states with different total spins S. Therefore our Hilbert space in numerical calculations is the following set of pairs $\{(6, 2), (6, 1), (6, 0), (4, 2), (4, 1), (4, 0), (2, 1), (4, 0), (2, 1), (4, 0), (2, 1), (4, 0)$ (2, 0).

If Hamiltonian contains only \mathcal{H}_t , the lowest energies of the N = 2, 4, 6 sectors are shown in Fig. 9(a). The N =6 sector has a lower energy than N = 4 sector. However choosing $\mu = 0, C = 0.2$, we find that the lowest energy



FIG. 9. (a) The lowest energies in N = 2, 4, 6 sectors of \mathcal{H}_i . (b) Including $\mu = 0, C = 0.2$, the lowest energies has been shifted so N = 4 sector has the lowest energy and it is in the (4,1) sector.

is in the N = 4 sector, see Fig. 9(b). The lowest energy state is in the (4, 1) sector because of our special choice of the profile of the Zeeman coupling in *z* direction [see Fig. 8(b)], guaranteeing that (4, 1) states are more stable than (4, 2) and (4, 0) states. There are other ways to choose μ and *C* in order to make (4, 1) the lowest energy states. We choose this special set because the half width of the BCS wave function is of the order of \sqrt{N} [49] so N = 2, 4, 6sectors all play important roles in the ground-state properties. Therefore a change of μ and *C* will not affect the topological properties of the system. Experimentally *C* should be a fixed number for the system and we only need to tune the chemical potential μ .

Now we include the H_{sc} and H_{bx} into the simulations. The special choice of a localized H_{bx} allows us to focus only on a single domain wall. The edge states on the other domain wall will be gapped out due to the proximity superconducting order. In our system, the emergence of the parafermion mode means the appearance of a sixfold ground-state degeneracy. Exactly diagonalizing Hamiltonian Eq. (33), we obtain the spectra shown in Fig. 10. In Fig. 10(a), we fixed the value of B and change the superconducting pairing Δ . We find that the system evolve from a single ground state to a threefold ground state, and finally to a sixfold ground state. Based on general consideration of Sec. V, we assume that this sixfold groundstate degeneracy represents the emergence of parafermions. The six states do not have exactly the same energy like in Sec. V. The reason is, arguments of Sec. V apply, strictly speaking, for 1D systems, while our simulation treats a 2D system. Hence the degeneracy is lifted because of a possible tunneling between the edge states and other bulk orbitals. We observe that when the pairing potential is further increased, the system evolves into a threefold degenerate state. The reason for this effect can be the system entering a gapped phase dominated by Δ . In Fig. 10(b), we fix the value of the order parameter Δ and change the in-plane field B. We observe that the sixfold degenerate ground states appear at experimentally feasible B of a few tesla that will not alter the spin state of the fractional quantum Hall liquid. When B is increased further, provided the spin states of neighboring FQHE liquids are not altered, the system can enter a tunneling dominated gapped regime with threefold degenerate ground state. Thus by exact diagonalization we find that the system can enter a phase which has sixfold degenerate ground state. In our calculation with six particles, charging energy restriction made the relevant values of Δ and *B* quite experimentally feasible. The calculation, of course, must be extended to systems with larger number of particles in order to confirm this result.



FIG. 10. (a) The energy dependence on superconducting pairing potential Δ with a fixed B = 1 T. Red rectangles indicate the range of parameters for the sixfold degenerate ground-state subspace, which is separated from the bulk by a gap. This is the evidence for the appearance of parafermion modes. Green reactngle corresponds to a region, in which degeneracy tends to threefold. (b) The energy dependence on the in plane magnetic field with a fixed $\Delta = 0.05$ meV. The sixfold ground-state degeneracy also appears and persists for a broader parameter regime. The energy is measured in units of $\frac{e^2}{e l_B}$.

To analyze the properties of the system further, we plot the phase diagram of the system in a wide range of Δ and *B* in Fig. 11. We find that the phase A, which has sixfold ground-state degeneracy (represented by red in Fig. 11), is separated from other gapped phases by a gapless incompressible regime. When we go from other gapped phases to phase A, the gaps first close and then reopen. A quantum phase transition may occur during this process. Combining numerical results with the analytic consideration, we conclude that it is legitimate to call the phase A the topological superconducting phase that supports parafermions.



FIG. 11. The phase diagram of our system. The red region represents states which has sixfold ground-state degeneracy. The green region represents states which has threefold ground-state degeneracy. Black region represents gapless states. We identify a gap, when the maximum energy difference between candidate states should be at least two times as large as the second maximum energy difference. In this phase diagram, we observe that the sixfold ground-state degeneracy regime are separated from other gapped states by gapless regions, which means that a quantum phase transition may occur between these regimes. We identify the phase represented by the red region as the topological superconducting phase supporting parafermion zero modes.

VII. PARAFERMION SETTINGS BASED ON v = 4/3 AND 5/3 SPIN TRANSITIONS

Spin transitions in the fractional quantum Hall effect can also be observed at filling factors v = 4/3 and 5/3. In experiments on CdMnTe such a prominent transition at v = 5/3 was observed in [43]. CdMnTe experiment at v = 4/3, although less prominently, also suggests a possible spin transition. These transitions can be easily understood both in terms of electron Landau level and composite fermion Landau (Λ) level pictures.

In terms of electron Landau levels, at low but quantizing magnetic fields, the splitting between spin-resolved Landau levels is dominated by a large positive contribution of s - dexchange between electrons and Mn ions. The ground orbital Landau level in CdMnTe in magnetic fields about 3 T is the ground orbital Landau level with spin down $(0, \downarrow)_e$, and the next partially filled electron Landau level (1/3 or 2/3 filled for $\nu = 4/3$ and 5/3, correspondingly) is the first excited orbital Landau level with the same spin, $(1, \downarrow)_e$. While a positive exchange contribution to Zeemann splitting E_{ex} becomes saturated at low magnetic fields and is independent of the magnetic field, the bulk negative g factor leads to decrease of the Zeemann splitting $\hbar\Omega_Z$ with an increase of the magnetic field. At the magnetic field such that $\hbar\omega_e - \hbar\omega_Z - E_{ex} = 0$, levels $(0, \uparrow)_e$ and $(1, \downarrow)_e$ would cross in the absence of spinorbit interactions. Instead, spin-orbit interaction leads to an anticrossing of Landau levels and anticrossing of the corresponding edge states [22,23,50]. Nevertheless, at magnetic fields higher than the anticrossing field, the electron Landau level that is predominantly $(0, \uparrow)_e$ becomes partially filled. Due to this transition the total electron spin polarization decreases from 5/3 = 1 + 2/3 to 1/3 = 1 - 2/3 for $\nu = \frac{5}{3}$, and from 4/3 = 1 + 1/3 to 2/3 = 1 - 1/3 for $\nu = 4/3$, while the spin polarization of electrons in the first excited electron Landau level changes sign.

While this electron picture does not take into account electron-electron interactions, it is important for understanding these transitions, because it clearly shows that the transition involves anticrossing of levels and can be controlled via spin-orbit interactions. However, in order to understand the edge states of the system, we turn our attention to consideration of the composite fermion picture.

The v = 4/3 fractional quantum Hall state is a particlehole symmetric to the principal states, 4/3 = 2 - 2/(4 - 1)and can be described by two filled composite fermion Landau levels. In quantizing but sufficiently low magnetic fields in CdMnTe, these two filled CF hole levels are $(0, \downarrow)_{cf}$ and $(1, \downarrow)_{cf}$, representing a spin-polarized CF phase. At sufficiently high magnetic fields, the two filled levels are $(0, \downarrow)_{cf}$ and $(0, \uparrow)_{cf}$, and composite fermions become spinunpolarized. At the true boundary of the sample, the edge starts with bulk density 4/3, raises to density 2, decreases to density 1 and then goes to 0 [26]. The edge corresponding to the filled ground level v = 1 goes around the sample, and can be removed from low-energy theory from the internal boundary between two differently spin-polarized regions. At this boundary, for one of the phases we have two hole composite fermion edges responding to $(0, \downarrow)_{cf}$ and $(1, \downarrow)_{cf}$ Lambda levels closer to the bulk of the corresponding region, followed by the outer edge corresponding to the electron Landau level $(1, \downarrow)_e$. For the other phase region, the internal CF hole edges correspond to $(0, \downarrow)_{cf}$ and $(0, \uparrow)_{cf} \Lambda$ levels, and the outer edge corresponding to electron Landau level $(0, \uparrow)_e$. The question now arises whether any of the edges can be removed from low-energy picture. Generally 1/3 charge quasiparticles cannot tunnel through the region of charge 1 quasiparticles, and that is a correct statement for the true edge of the sample. However, the closest edge states in the domain wall originating from the Landau levels $(1,\downarrow)_e$ and $(0,\uparrow)_e$ become hybridized and form a helical domain wall, which conducts in the presence of impurities or smooth random potential and constitutes a compressible region [23]. Hence there is no longer a prohibition for 1/3charge channel to tunnel and couple to another 1/3 charge through this compressible channel. Then, by using the argument similar to that in Sec. II, we can remove edge states corresponding to $(0, \downarrow)_{cf}$ in both phases from the low-energy sector. The remaining $(0, \uparrow)_{cf}$ and $(1, \downarrow)_{cf}$ states constitute two counterpropagating hole charge 1/3 states with opposite spin. Interestingly enough, they coexist with a helical domain wall made of hybridized $(1, \downarrow)_e$ and $(0, \uparrow)_e$ electron channels. However, the superconducting coupling and spin-flipping interaction can still produce gaps for1/3 charge counterpropagating states with opposite spins, leading to parafermions. At the same time, a helical domain wall made of hybridized $(1, \downarrow)_e$ and $(0, \uparrow)_e$ channels will result in Majrorana modes [23].

The $\nu = 5/3$ fractional quantum Hall state and spin transition is desribed similarly, see Fig. 12. 5/3 = 2 - 1/(2 + 1)and can be described by one filled composite fermion hole Landau level. In weaker magnetic fields, this is the $(0, \downarrow)_{cf}$ hole level, and in higher magetic fields, this is the $(0, \uparrow)_{cf}$ hole level. However, analysis shows that at the domain wall boundary between two phases with different spin polarization, these two CF edge states are again separated by a helical domain



FIG. 12. The domain wall and edge states at v = 5/3. Electrons occupy $(0, \downarrow)_e$ and $(0, \uparrow)_e$ Landau levels in a phase with total spin density 5/3 and $(0, \downarrow)_e$ and $(1, \downarrow)_e$ Landau levels in a phase with total spin density 1/3. The outermost black edge channel around both regions is integer $(0, \downarrow)_e$ edge. Closest edges in the domain wall area are edges corresponding to integer levels $(0, \uparrow)_e$ (blue) and $(1, \downarrow)_e$ (red). The innermost levels are composite fermion hole Λ levels $(0, \downarrow)_{cf}$ (red) and $(1, \uparrow)_{cf}$ (blue)

wall made of hybridized $(1, \downarrow)_e$ and $(0, \uparrow)_e$ electron channels. Similarly to $\nu = \frac{4}{3}$ domain wall, $\nu = \frac{5}{3}$ domain wall suggests coexistense of parafermions and Majorana fermions. The structure of the domain wall in this case exhibits coexisting $(1, \downarrow)_e$ and $(0, \uparrow)_e$ edges and $(0, \downarrow)_{cf} (1, \uparrow)_{cf}$ edges.

An interesting question emerges whether the spin-flip gapping mechanism for the $(0, \uparrow)_{cf}$ and $(1, \downarrow)_{cf}$ counterpropagating CF hole states, can be stronger due to spin-orbit interactions, in contrast to similar CF states discussed in Sec. II. For $\nu = 2/3$ states, composite fermion states are produced by default from electron states of the ground Landau level. If our starting point is these ground Landau level states, and we consider spin-orbit interactions as a perturbation, then all intra-Landau level spin-orbit matrix elements vanish, and spin-orbit coupling does not have any effect in the bulk. In the Appendix, we demonstrate that for the domain wall that defines a mid-plateau peak in the resistivity, the edge states of $(0, \uparrow)_{cf}$ and $(1, \downarrow)_{cf}$ composite fermions levels are characterized by an extremely small spin-orbit gap.

The $\nu = 4/3$ states in CdMnTe originate from full $(0, \downarrow)_e$ Landau level and $(0, \uparrow)_e$ Landau level in the phase with 2/3total spin polarization, and from full $(0, \downarrow)_e$ Landau level and from $(1, \downarrow)_e$ Landau level in the phase with 4/3 total spin polarization. In the latter case, if we include $(1, \downarrow)_e$ level into a starting point for composite fermions, we clearly go beyond lowest Landau level approach to composite fermions. However, large exchange splitting that is nearly independent of magnetic feild in CdMnTe makes the $(1, \downarrow)_e$ Landau level much lower in energy than $(0, \uparrow)_e$ state in a wide range of magnetic fields. Lowest Landau level restriction is justified, of course, in the limit of very large magnetic fields. However, spin transitions, crossing and anticrossing of levels take place at much smaller fields, and their consideration with inclusion of higher electron Landau levels is justified. Once the $(1, \downarrow)_e$ level is included in the Hilbert space for evaluating interactions, the spin-orbit effects become important.

To illustrate the importance of spin-orbit effects, it is also worth emphasising that when spin-orbit effects are sizable, it is of interest to consider the problem explicitly taking into account spin-orbit interactions right from the start of investigating the quantum Hall system. CdMnTe quantum wells are affected by the spin-orbit interactions of Rashba type [51], which can be described by the spin-dependent vector potential [52–54], which acts together with electromagnetic vector potential defined by the magnetic field. In a perpendicular magnetic field $\mathbf{H} = (0, 0, H)$ the electron Hamiltonian is given by

$$\mathcal{H} = \frac{1}{2m^*} \left(\mathbf{p} - \frac{e}{c} \mathbf{A} + \mathbf{A}_{\rm so} \right)^2 + \frac{1}{2} (g\mu H + E_{\rm ex}) \boldsymbol{\sigma}_z, \quad (39)$$

where **A** is the magnetic vector potential, the spin-dependent vector potential $\mathbf{A}_{so} = \alpha m(\sigma_y, -\sigma_x, 0)$, m^* , and g is the effective electron mass and g factor, correspondingly, and E_{ex} is the contribution of Mn ions in the spin splitting of electron levels taken in the mean-field approximation. We assume the Rashba constant to be spatially independent and include constant energy term $\alpha^2 m$ into electron Hamiltonian. The energy eigenvalues for this problem are given by

$$E_0 = \frac{1}{2}(\hbar\omega_c + g\mu H + E_{\rm ex}) + \alpha^2 m, \qquad (40)$$

$$E_{n,\pm} = \hbar\omega_c n + \alpha^2 m$$

$$\pm \sqrt{\frac{1}{4}(g\mu H + E_{\text{ex}} + \hbar\omega_c)^2 + (\hbar\alpha/\ell_m)^2 n}. \quad (41)$$

The eigenfunctions have the following form:

$$\psi_0 = \begin{pmatrix} u_0 \\ 0 \end{pmatrix}; \quad \psi_{n,\pm} = \begin{pmatrix} a_{n,\pm}u_n \\ b_{n,\pm}u_{n-1}, \end{pmatrix}, \tag{42}$$

where spinor coefficients $a_{n,\pm}$ and $b_{n,\pm}$ are nonzero, and $|a_{n,\pm}|^2 + |b_{n,\pm}|^2 = 1$

For electrons in CdMnTe at small magnetic fields, due to large E_{ex} , the ground-state energy is $E_{1,-}$, and the first excited level has energy $E_{2,-}$. The electron spectrum is characterized both by crossings, e.g., of E_0 and $E_{1,-}$ levels, and by anticrossings, e.g., of $E_{2,-}$ and E_0 levels. Is is noteworthy that spin in the ground level at small fields deviates from z direction due to spin-orbit interactions, hence it is certainly important for composite particles in this regime.

We now include spin-orbit interactions in the Chern-Simons procedure. The mean-field Hamiltonian of the system reads

$$\mathcal{H} = \frac{1}{2m^*} \left(\mathbf{p} - \frac{e}{c} \mathbf{A}^* + \mathbf{A}_{so} \right)^2 + \frac{1}{2} (g\mu H + E_{ex}) \boldsymbol{\sigma}_z + V, \quad (43)$$

where A^* is the effective vector potential that takes into account both external magnetic and average Chern-Simons magnetic field, and *V* are electron-electron interactions. The

naive solution for energies of composite fermion levels becomes

$$E_0 = \frac{1}{2}(\hbar\omega_c^* + g\mu H + E_{\rm ex}) + \alpha^2 m,$$
 (44)

$$E_{n,\pm} = \hbar \omega_c^* n + \alpha^2 m \pm \sqrt{\frac{1}{4} (g \mu H + E_{\text{ex}} + \hbar \omega_c^*)^2 + (\hbar \alpha / \ell_m^*)^2 n}, \quad (45)$$

Thus, in the naive solution, in addition to the effective magnetic field defining the cyclotron frequency, the spin-orbit term is also expressed in terms of magnetic length characterizing the effective rather than the external magnetic field. It is, of course clear, that this spectrum has to be renormalized by interactions. Nevertheless, it is apparent that it can be characterized by both crossings and anticrossings. Edge channels originating from CF levels that experience anticrossing can be strongly gapped by spin-orbit interactions.

VIII. SUMMARY

In this paper, we have considered first the domain wall between spin-polarized and spin-unpolarized regions of the 2D electron liquid in v = 2/3 fractional quantum Hall state. Analytic considerations show that the domain wall between the spin-polarized and spin-unpolarized regions of the 2D electron liquid hosts two edge states that are counterpropagating and have opposite spin polarization. This picture is confirmed using numerical calculations in a disk and torus geometries. We proved both analytically and numerically that the edge states can support parafermions when the domain wall area is proximity-coupled to an s-wave superconductor. Hilbert space for exact diagonalization study significantly increases due to account of superconducting correlations. We have discussed control of parafermion zero modes due to hybridization of edge states by spin-flipping interactions. In GaAs for $\nu = 2/3$ spin transitions, a tilted magnetic field with an in-plane component controlling spins can be used for gapping edge channels, while spin-orbit interactions are negligible. In v = 4/3 and 5/3 spin transitions in fractional quantum Hall effect in CdMnTe, parafermions modes also emerge and can be controlled by electrostatic gates due to sizable spin-orbit anticrossing gap. We discuss near absence of spin-orbit coupling for composite fermions at v = 2/3for all principal composite fermion states, and emergence of spin-orbit interactions in systems like CdMnTe in the presence of exchange splitting of electron states. In these systems, spin-orbit interactions arise for states that are particle-hole symmetric to the principal states in the presence of spin, such as v = 4/3 and 5/3.

Experimental observation of spin phase transitions in fractional quantum Hall effect is not limited to the lowest orbital Landau level spin states even in nonmagnetic semiconductors [42]: *s* state with filling factor 8/3 has been shown experimentally to support a spin transition in GaAs. This observation further validates inclusion of the first excited Landau level spin spin states into composite fermion picture, as we discussed for filling factor 4/3 and 5/3 states. In terms of composite fermion model of spin transitions based on crossing of CF Landau levels, filling factor 8/3 state is similar to 2/3in the ground Landau level. This supports the idea of possible parafermionic states in the setting of first excited electron Landau level and potentially opens experimental opportunities to use lower range of magnetic fields, improving conditions for generating superconducting order in induced domain walls between different spin phases.

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APPENDIX: SPIN-FLIPPING INTERACTIONS IN THE LOWEST LANDAU LEVEL

Tunneling between two counterpropagating fractional quantum Hall edge states with opposite spin polarization requires spin-flip interactions. One candidate is spin-orbit interaction suggested for setting considered in Ref. [18], and the other is spin-flip due to an in-plane component of a tilted magnetic field. We now analyze the viability of these interactions for generating tunneling gap.

The crossing in quasiparticle spectra in our system occurs between composite fermion levels. In consideration at the level of composite fermions, the "orbital quantization" energy, or cyclotron frequency is entirely determined by the intra lowest Landau level electron-electron processes. Landau level mixing can not change the picture as long as one always considers electrons of the ground electron level as giving rise to composite fermion quasiparticles. For this reason, the dispersion of composite fermions is defined by the Coulomb energy, and the effective band mass of electron plays no role. Composite fermions couple to the effective magnetic field, defined by a compensation of the external magnetic field and the Chern-Simons field. In contrast, Zeeman coupling of composite fermions is described by the value of the electron gfactor and an external magnetic field.

Considering composite fermions microscopically, one generally has to start from spin up and down electrons of the ground Landau level and include electron-electron interactions. Spin-orbit interactions, such as the Rashba or Dresselhaus spin-orbit coupling can be included perturbatively. It is clear, however, that for the "bulk" 2D electrons, the matrix elements of the spin-orbit coupling between up and dow states with the same orbital wave function simply vanish. That is not the case for transitions between "edge" modes. Indeed, our setting includes either two electrostatic gates with differing voltages, leading to different electron densities underneath them and ultimately to composite fermion level structure shown in Fig. 2(a), or can be described by the varying electron Zeeman coupling leading to the same picture. In both cases, electrons in the domain wall that eventually become composite fermion edge states are subject to a spin-dependent potential and the corresponding electric field that is opposite for the two electron spin directions.

Then the lowest Landau level wave functions for two spin directions in the Landau gauge with magnetic field $\mathbf{H} \parallel z$ vector potential $\mathbf{A} = (0, Hx, 0)$ and spin-dependent electric fields in *x* direction with magnitude *E* are given by

$$\Psi_{\uparrow} = \exp ik_y y \frac{\exp\left[-\frac{1}{2}\left(\frac{x-x_{\uparrow}}{l_m}\right)^2\right]}{\sqrt{l_m}},$$
 (A1)

$$\Psi_{\downarrow} = \exp ik_y y \frac{\exp\left[-\frac{1}{2}\left(\frac{x-x_{\downarrow}}{l_m}\right)^2\right]}{\sqrt{l_m}},$$
 (A2)

where

$$x_{\uparrow} = -l_m^2 k_y - \frac{eE l_m^2}{\hbar \omega_c},\tag{A3}$$

$$x_{\downarrow} = -l_m^2 k_y + \frac{eE l_m^2}{\hbar \omega_c},\tag{A4}$$

 ω_c is the electron cyclotron frequency and k_y is the electron wave vector along the domain wall. Ψ 's are the wave functions in the corresponding crossed electric and magnetic fields. These two wave functions are not orthogonal due to different x_{\uparrow} and x_{\downarrow} . The matrix element of the, e.g., Rashba spinorbit interaction described by the Hamiltonian $H_R = \alpha(\sigma_x k_y - \sigma_y k_x)$, with $k_x = -i\frac{\partial}{\partial x}$, is given by

$$\langle \Psi_{\uparrow} | H_R | \Psi_{\downarrow} \rangle = \alpha \frac{eE}{\hbar \omega_c} \exp\left[-\left(\frac{eE l_m}{\hbar \omega_c}\right)^2\right].$$
 (A5)

At electric field E = 0, the spin-orbit matrix element vanishes, as it should be in the bulk 2D electrons case. Equation (A5) is a perturbative result obtained using the lowest Landau orbital wave functions, but it contains $\hbar\omega_c$ in the denominator as if it is related to an admixture of a higher Landau level. This is not accidental. Indeed using consideration of Rashba interaction in the previous section, the result (A5) can then be obtained in the leading order by calculating the matrix element of the interaction describing the spin-dependent electric field, $H_E = eEx\sigma_z$ between two exact bulk spin-orbit states.

We now consider the magnitude of the spin-orbit gap for edge modes, which is governed by the magnitude of the electric field E. The experimentally possible narrowest domain wall (in the x direction) is approximately 50 nm, and so that the magnitude of the gap is defined by the difference of energies of the like spins underneath the two electrostatic gates, Fig. 2(a). This value of this energy difference, however, is strongly restricted by the requirement that the fractional quantum Hall system underneath both gates is within the v = 2/3 quantum Hall plateau. Such restriction means that the difference of energies on the left and right of the domain wall is limited by the Zeeman energy that corresponds to the length of the interval of magnetic fields corresponding to the plateau, i.e., the plateau width. In experiments [24], where the domain wall in the fractional quantum Hall effect was observed and electrostatically controlled, the measured width of the plateau is $\delta B = 0.35T$. In this case the magnitude of the spin-orbit matrix element in GaAs system is negligibly small $\sim 1-2 \ \mu eV$.

Therefore for the domain wall setting, experimentally feasible in-plane Zeeman field of order of 1 T, that leads to a tunneling gap sufficient for the emergence of parafermions in our modeling, becomes a preferential mechanism for generating a hybridization of edge states with opposite spin and a corresponding tunneling gap.

The situation changes, however, for a settings based on spin transitions at v = 4/3 and 5/3 in a system like CdMnTe [43] discussed in Sec. VII. In both of these cases, edge states near a tentative spectral crossing belong to different electron Landau levels, and spin-orbit interactions result in anticrossing with an anticrossing gap in CdMnTe of the order to $50 \ \mu eV$ [23]. This spin-orbit gap can be effectively controlled by the electrostatic gate, which then can control emerging parafermions similarly to control of Majorana zero modes in Ref. [23]. This allows then to use in-plane magnetic field as an independent knob, opening additional opportunities for performing braiding operations [55,56].

- W. P. Su, J. R. Schrieffer, and A. J. Heeger, Solitons in Polyacetilene, Phys. Rev. Lett. 42, 1698 (1979).
- [2] J. M. Leinaas and J. Murheim, On the theory of identical particles, IL Nuovo Cimento 37, 1 (1977).
- [3] F. Wilczek, Magnetic-Flux, Angular Momentum and Statistics, Phys. Rev. Lett. 48, 1144 (1982).
- [4] J. Fröhlich, Statistics of fields, the Yang-Baxter equation, and the theory of knots and links, *Nonperturbative Quantum Field Theory* (Springer, Boston, MA, 1988), pp. 71–100.
- [5] G. Moore and N. Read, Nonabelions in the fractional quantum Hall effect, Nucl. Phys. B 360, 362 (1991).
- [6] X.-G. Wen, Non-Abelion Statistics in the Fractional Quantum Hall Effect, Phys. Rev. Lett. 66, 802 (1991).
- [7] N. Read and D. Green, Paired states of fermions in two dimensions with breaking of parities and time-reversal symmetries and the fractional quantum Hall effect, Phys. Rev. B 61, 10267 (2000).

- [8] D. A. Ivanov, Non-Abelian Statistics of Half-Quantum Vortices in Superconductors, Phys. Rev. Lett. 86, 268 (2001).
- [9] A. Yu. Kitaev, Unpaired Majorana fermions in quantum wires, Phys. Usp. 44, 131 (2001).
- [10] C. Nayak, S. H. Simon, A. Stern, M. Freedman, and S. Das Sarma, Non-Abelian anyons and topological quantum computation, Rev. Mod. Phys. 80, 1083 (2008).
- [11] J. D. Sau, R. M. Lutchyn, S. Tewari, and S. D. Sarma, Generic New Platform for Topological Quantum Computation Using Semiconductor Heterostructures, Phys. Rev. Lett. **104**, 040502 (2010).
- [12] J. Alicea, Y. Oreg, G. Refael, F. V. Oppen, and M. P. A. Fisher, Non-Abelian statistics and topological quantum information processing in 1d wire networks, Nat. Phys. 7, 412 (2011).
- [13] M. H. Freedman, M. J. Larsen, and Z. Wang, The twoeigenvalue problem and density of Jones representation of braid groups, Commun. Math. Phys. 228, 177 (2002).

- [14] M. Baraban, N. E. Bonesteel, and S. H. Simon, Resources required for topological quantum factoring, Phys. Rev. A 81, 062317 (2010).
- [15] P. Fendley, Parafermionic edge zero modes in Z_n -invariant spin chains, J. Stat. Mech.: Theory Exp. (2012) P11020.
- [16] J. Alicea and P. Fendley, Topological phases with parafermions: theory and blueprints, Annu. Rev. Condens. Matter Phys. 7, 119 (2016).
- [17] R. S. K. Mong, D. J. Clarke, J. Alicea, N. H. Lindner, P. Fendley, C. Nayak, Y. Oreg, A. Stern, E. Berg, K. Shtengel, and M. P. A. Fisher, Universal Topological Quantum Computation from a Superconductor-Abelian Quantum Hall Heterostructure, Phys. Rev. X 4, 011036 (2014).
- [18] D. J. Clarke, J. Alicea, and K. Shtengel, Exotic non-Abelian anyons from conventional fractional quantum Hall states, Nat. Commun. 4, 1348 (2013).
- [19] J. P. Eisenstein, H. L. Stormer, L. N. Pfeiffer, and K. W. West, Evidence for a spin transition in the $\nu = 2/3$ fractional quantum Hall effect, Phys. Rev. B **41**, 7910 (1990).
- [20] J. H. Smet, R. A. Deutschmann, W. Wegscheider, G. Abstreiter, and K. von Klitzing, Ising Ferromagnetism and Domain Morphology in the Fractional Quantum Hall Regime, Phys. Rev. Lett. 86, 2412 (2001).
- [21] J. K. Jain, *Composite Fermions* (Cambridge University Press, Cambridge, UK, 2003).
- [22] A. Kazakov, G. Simion, Y. Lyanda-Geller, V. Kolkovsky, Z. Adamus, G. Karczewski, T. Wojtowicz, and L. P. Rokhinson, Mesoscopic Transport in Electrostatically Defined Spin-Full Channels in Quantum Hall Ferromagnets, Phys. Rev. Lett. 119, 046803 (2017).
- [23] G. Simion, A. Kazakov, L. P. Rokhinson, T. Wojtowicz, and Y. B. Lyanda-Geller, Disorder-generated non-Abelions, Phys. Rev. B 97, 245107 (2018).
- [24] T. Wu, A. Kazakov, G. Simion, Z. Wan, J. Liang, K. W. West, K. Baldwin, L. N. Pfeiffer, Y. Lyanda-Geller, and L. P. Rokhinson, Parafermion supporting platform based on spin transitions in the fractional quantum Hall effect regime, Phys. Rev. B 97, 245304 (2018).
- [25] A. H. MacDonald, Edge States in the Fractional-Quantum-Hall-Effect Regime, Phys. Rev. Lett. 64, 220 (1990).
- [26] C. W. J. Beenakker, Edge Channels for the Fractional Quantum Hall Effect, Phys. Rev. Lett. 64, 216 (1990).
- [27] M. D. Johnson and A. H. MacDonald, Composite Edges in the $\nu = 2/3$ Fractional Quantum Hall Effect, Phys. Rev. Lett. 67, 2060 (1991).
- [28] X.-G. Wen and A. Zee, Topological structures, universality classes, and statistics screening in the anyon superfluid, Phys. Rev. B 44, 274 (1991).
- [29] X.-G. Wen, Theory of the edge states in fractional quantum Hall effects, Int. J. Mod. Phys. B **6**, 1711 (1992).
- [30] C. de C. Chamon and X. G. Wen, Sharp and smooth boundaries of quantum Hall liquids, Phys. Rev. B 49, 8227 (1994).
- [31] D. B. Chklovskii, Structure of fractional edge states: A composite-fermion approach, Phys. Rev. B 51, 9895 (1995).
- [32] X.-G. Wen, Topological orders and edge excitations in fractional quantum Hall states, Adv. Phys. 44, 405 (1995).
- [33] L. S. Levitov, A. V. Shytov, and B. I. Halperin, Effective action of a compressible quantum Hall state edge: Application to tunneling, Phys. Rev. B 64, 075322 (2001).

- [34] A. Lopez and E. Fradkin, Effective field theory for the bulk and edge states of quantum Hall states in unpolarized single layer and bilayer systems, Phys. Rev. B 63, 085306 (2001).
- [35] I. A. McDonald and F. D. M. Haldane, Topological phase transition in the $\nu = 2/3$ quantum Hall effect, Phys. Rev. B 53, 15845 (1996).
- [36] J. E. Moore and F. D. M. Haldane, Edge excitations of the ν = spin-singlet quantum Hall state, Phys. Rev. B 55, 7818 (1997).
- [37] Z. X. Hu, H. Chen, K. Yang, E. H. Rezayi, and X. Wan, Ground state and edge excitations of a quantum Hall liquid at filling factor 2/3, Phys. Rev. B 78, 235315 (2008).
- [38] Y.-H. Wu, G. J. Sreejith, and J. K. Jain, Microscopic study of edge excitations of spin-polarized and spin-unpolarized $\nu =$ 2/3 fractional quantum Hall effect, Phys. Rev. B **86**, 115127 (2012).
- [39] J. Wang, Y. Meir, and Y. Gefen, Edge Reconstruction in the $\nu = 2/3$ Fractional Quantum Hall State, Phys. Rev. Lett. **111**, 246803 (2013).
- [40] L. Fu and C. L. Kane, Superconducting Proximity Effect and Majorana Fermions at the Surface of a Topological Insulator, Phys. Rev. Lett. **100**, 096407 (2008).
- [41] J. Alicea, New directions in the pursuit of Majorana fermions in solid state systems, Rep. Prog. Phys. 75, 076501 (2012).
- [42] W. Pan, K. W. Baldwin, K. W. West, D. C. Pfeiffer, and L. N. Tsui, Spin Transition in the $\nu = 8/3$ Fractional Quantum Hall Effect, Phys. Rev. Lett. **108**, 216804 (2012).
- [43] C. Betthausen, P. Giudici, T. Iankilevitch, C. Preis, V. Kolkovsky, M. Wiater, G. Karczewski, A. Piot, J. Kunc, M. Potemski, T. Wojtowicz, and D. Weiss, Fractional quantum Hall effect in a dilute magnetic semiconductor, Phys. Rev. B 90, 115302 (2014).
- [44] D. Yoshioka, B. I. Halperin, and P. A. Lee, Ground State of Two-Dimensional Electrons in Strong Magnetic Fields and 1/3 Quantized Hall Effect, Phys. Rev. Lett. 50, 1219 (1983).
- [45] X.-G. Wen and Q. Niu, Ground-state degeneracy of the fractional quantum hall states in the presence of a random potential and on high-genus Riemann surfaces, Phys. Rev. B 41, 9377 (1990).
- [46] X.-G. Wen, Quantum Field Theory of Many-Body Systems: From the Origin of Sound to an Origin of Light and Electrons (Oxford University Press on Demand, New York, 2004).
- [47] For a different choice of the gauge potential describing a magnetic field, several matrix elements could be significant. The chosen gauge is uniquely convenient and suitable to elucidate superconducting coupling of the two closest conterpropagating states with opposite spins comprising the domain wall. The magnitude of this coupling is essentially treated as a parameter.
- [48] C. Repellin, A. M. Cook, T. Neupert, and N. Regnault, Numerical investigation of gapped edge states in fractional quantum Hall-superconductor heterostructures, NPJ Quantum Materials 3, 14 (2018).
- [49] P. G. de Gennes, *Superconductivity of Metals and Alloys* (Addison Wesley, Redwood City, CA, 1989).
- [50] A. Kazakov, G. Simion, Y. Lyanda-Geller, V. Kolkovsky, Z. Adamus, G. Karczewski, T. Wojtowicz, and L. P. Rokhinson, Electrostatic control of quantum Hall ferromagnetic transition:

A step toward reconfigurable network of helical channels, Phys. Rev. B **94**, 075309 (2016).

- [51] E. I. Rashba, Properties of semiconductors with an extremum loop. 1. Cyclotron and Combinational resonance in a magnetic field perpendicular to the plane of the loop, Sov. Phys. Solid State 2, 1109 (1960).
- [52] Y. Lyanda-Geller and A. D. Mirlin, Novel Symmetry of a Random Matrix Ensemble: Partially Broken Spin Rotation Invariance, Phys. Rev. Lett. 72, 1894 (1994).
- [53] S. V. Iordanskii, Y. B. Lyanda-Geller, and G. E. Pikus, Weak localization in quantum wells with spin-orbit interactions, JETP Lett. 60, 206 (1994).
- [54] G. Simion and Y. Lyanda-Geller, Magnetic field spectral crossings of Luttinger holes in quantum wells, Phys. Rev. B 90, 195410 (2014).
- [55] Y. Lyanda-Geller, Topological Transitions in Berry's Phase Interference Effects, Phys. Rev. Lett. 71, 657 (1993).
- [56] J. Li, T. Neupert, B. A. Bernevig, and A. Yazdani, Manipulating Majorana zero modes on atomic rings with an external magnetic field, Nat. Commun. 7, 10395 (2016).

Correction: The omission of a statement in the Acknowledgment section has been fixed.